Product data sheet

# NTM88Kxx5S

Tire pressure monitor sensor

Rev. 3.0 — 15 November 2024



## 1 General description

The NTM88 family consists of small (4 mm x 4 mm x 1.98 mm), fully integrated tire pressure monitoring sensors (TPMS). The devices described in this data sheet, NTM88Kxx5S, provide low transmitting power consumption, large customer memory size, and dual-axis accelerometer architecture. The NTM88Kxx5S TPMS solution integrates an 8-bit microcontroller (MCU), pressure sensor, accelerometers in two ranges, programmable RF transmitter and flexible LF receiver. The sensor supports seven GPIOs, client SPI, and a 2-channel timer / pulse-width module.

## 2 Features and benefits

- Optional pressure ranges<sup>1</sup>
- Optional accelerometer range: See <u>Section 3</u>.
- Transducer measurement interfaces with low-power AFE:
  - 10-bit compensated pressure sense element
  - 10-bit compensated accelerometers
  - 8-bit compensated internal device temperature measurement
  - 8-bit compensated internal device voltage measurement
  - Two I/O pins can be used for external signals
- 8-bit S08 compact instruction set controller:
  - 64 bytes low-power "always on" NVM parameter registers
  - 512 bytes SRAM
  - 16 kB flash memory (512 bytes reserved for NXP coefficients)
  - Family of NXP firmware libraries available via royalty-free license
- Programmable RF transmitter
  - Characterized for RF carrier typical of 315 MHz or 434 MHz
  - Characterized for FSK in ~3 kHz increments or OOK modulation
  - Characterized for baud rate examples of 9.6 kbp/s, 19.2 kbp/s, and 38.4 kbp/s
- Flexible 125 kHz LF receiver:
  - Capability for ASK or OOK demodulation
  - Automated Manchester decoding
- Two channel timer / pulse-width module
- · Client SPI to support host access to internal peripherals, registers, and memory
- Seven GPIOs with programmable multiplexing to support software development, external analog voltage input, timer, SPI, and wake-up
- Qualified in compliance with AEC-Q100, Rev. H

1 Consult NXP sales for details or specific requests.



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- · Long battery service life
- Internal temperature sensor
- Internal voltage sensor
- Six-channel, 8-, 10-, or 12-bit analog-to-digital converter with two external I/O inputs
- Internal 315 MHz/434 MHz RF transmitter
  - External crystal oscillator
  - PLL-based output with fractional-n divider
  - OOK and FSK modulation capability
  - Programmable data rate generator
  - Manchester, Bi-Phase, or NRZ data encoding
  - 256-bit RF data buffer variable length interrupt
  - Direct access to RF transmitter from MCU for unique formats
  - Low-power consumption
- · Differential input LF detector/decoder on independent signal pins
- Real-time Interrupt driven by LFO with intervals of 2, 4, 8, 16, 32, 64, or 128 ms
- · Free-running counter, low-power, wake up timer and periodic reset driven by LFO
- · Watchdog timeout with selectable times and clock sources
- Two-channel general-purpose timer/PWM module (TPM1)
- Internal oscillators
  - MCU bus clock of 0.5, 1, 2, and 4 MHz (1, 2, 4, and 8 MHz HFO)
  - Low frequency, low-power time clock (LFO) with 1 ms period
  - Medium frequency, controller clock (MFO) of 8 µs period
- · Low-voltage detection

## 3 Ordering information

#### Table 1. Ordering information

Type number	Package	Package						
	Name	ne Description Ver						
NTM88Kxx5S		Plastic thermal enhanced quad flat package; no leads, 0.1 dimple wettable flank; 24 terminals; 0.5 mm pitch, 4 mm x 4 mm x 1.98 mm body	SOT1931-1(D)					

#### Table 2. Ordering options

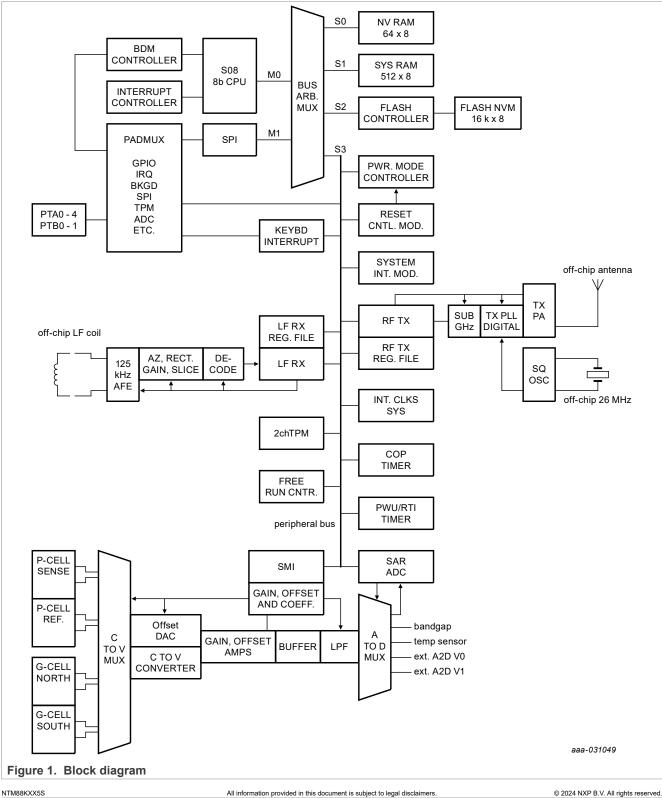
Part Number 'N8'	Pressure Range 'p'	Accelerometer 'aa'		X-axis Range	Z-axis Range	CodeH Hardware (First Rev) <sup>[1]</sup>
NTM88K135ST1	90 kPa to 1518 kPa 'K'	XZ	'13'	–80 g to +90 g	–360 g to +400 g	\$CD
NTM88K145ST1	90 kPa to 1518 kPa 'K'	XZ	'14'	-360 g to +400 g	-80 g to +90 g	\$CE
NTM88K155ST1	90 kPa to 1518 kPa 'K'	XZ	'15'	-360 g to +400 g	-360 g to +400 g	\$CF

[1] The value CodeF mentioned in the User Manual UM11227<sup>[1]</sup> depicts the version of firmware used by NXP during device tests, and will become \$FF as the device is shipped. The value of CodeF will be replaced again by the version number of the firmware library used by the customer at the time of device final application programming.

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## 4 Block diagram

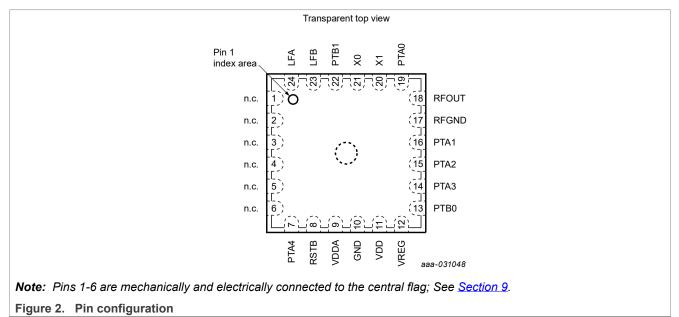
Figure 1 presents the device's main blocks and their signal interactions. Power management controls and bus control signals are not shown in this block diagram for clarity.



## **5** Pinning information

### 5.1 Pinning

A top view of the device pint with the pressure port on top is show in <u>Figure 2</u>. The orientation of the internal Z-axis accelerometer is shown in <u>Figure 3</u>.



### 5.2 Pin description

#### Table 3. Pin description

Symbol	Pin	Function	Description			
n.c.	1	—	Do not connect electrical signals to this pin; solder joint only.			
n.c.	2	—	Do not connect electrical signals to this pin; solder joint only.			
n.c.	3	—	Do not connect electrical signals to this pin; solder joint only.			
n.c.	4	—	Do not connect electrical signals to this pin; solder joint only.			
n.c.	5	—	Do not connect electrical signals to this pin; solder joint only.			
n.c.	6	—	Do not connect electrical signals to this pin; solder joint only.			
PTA4	7	PTA4 / BKGD	PTA4 Pin - The PTA4 pin places the device in the BACKGROUND DEBUG mode (BDM) to evaluate MCU code and transfer data to/from the internal memory. If the BKGD/PTA4 pin is held low when the device comes out of a power-on-reset (POR), the device switches into the ACTIVE BACKGROUND DEBUG mode (BDM).The BKGD/PTA4 pin has an internal pullup device or can be connected to VDD in the application, unless there is a need to enter BDM operation after the device as been soldered into the PWB. If in-circuit BDM is desired, the BKGD/PTA4 pin should be connected to VDD through a resistor (~10 kΩ or greater) which can be over-driven by an external signal. This resistor reduces the possibility of inadvertently activating the debug mode in the application due to an EMC event. When the application programs port A to GPIOs, PTA4 becomes output-only.			

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Table 3	Pin	descriptioncontinued
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Symbol	Pin	Function	Description
RST_B	8	Reset	The RST_B pin is an active-low hardware reset. When asserted, the MCU takes the reset vector. It is also used to establish a BDM connection and for other test purposes. The RST_B pin has an internal pullup device and can be connected to VDD in the application unless there is a need to enter BDM operation after the device as been soldered to the PWB. If in-circuit BDM is desired, the RST_B pin can be left unconnected; but should be connected to VDD through a low impedance resistor (<10 k $\Omega$ ) which can be over-driven by an external signal. This low impedance resistor reduces the possibility of getting into the debug mode in the application due to an EMC event. Activation of the external reset function occurs when the voltage on the RST_B pin goes below 0.3 × V <sub>DD</sub> for at least 100 ns before rising above 0.7 × V <sub>DD</sub> .
VDDA	9	Analog supply	The analog circuits operate from a single power supply connected to the unit through the VDDA pin. VDDA is the positive supply and GND is the ground. The conductors to the power supply should be connected to the VDDA and GND pins and locally decoupled. Care should be taken to reduce measurement signal noise by separating the VDD, GND, VDDA, and RFGND pins using a "star" connection such that each metal trace does not share any load currents with other external devices.
GND	10	Digital and analog ground	The digital and analog circuits operate from a single power supply connected to the unit through the VDD, VDDA, and GND pins. GND is the ground. Care should be taken to reduce measurement signal noise by separating the GND and RFGND pins using a "star" connection such that each metal trace does not share any load currents with other external devices.
VDD	11	Digital supply	The digital circuits operate from a single power supply connected to the unit through the VDD and GND pins. VDD is the positive supply. The conductors to the power supply should be connected to the VDD and GND pins and locally decoupled.
VREG	12	1.8 V regulation	The internal regulator for the RF analog circuits requires an external stabilization capacitor to GND.
РТВО	13	PTB0 / TPMCH0 / AD3	The PTB[0] pin is a general-purpose I/O pin. This pin can be configured as a nominal bidirectional I/O pin with programmable pullup devices. User software must configure the general-purpose I/O pin (PTB[1:0]) so that they do not result in "floating" inputs. PTB0 can be mapped to TPM channel 0, or to ADC channel 3.
РТАЗ	14	PTA3 / KBI3 / MOSI	The PTA[3] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in "floating" inputs. PTA[3] maps to keyboard interrupt function bit [3]. When SPI is enabled, PTA[3] serves as MOSI.
PTA2	15	PTA2 / KBI2 / MISO	The PTA[2] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in "floating" inputs. PTA[2] maps to keyboard interrupt function bit [2]. When SPI is enabled, PTA[2] serves as MISO.
PTA1	16	PTA1 / KBI1 / SCLK	The PTA[1] pin is a general-purpose I/O pin. The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in

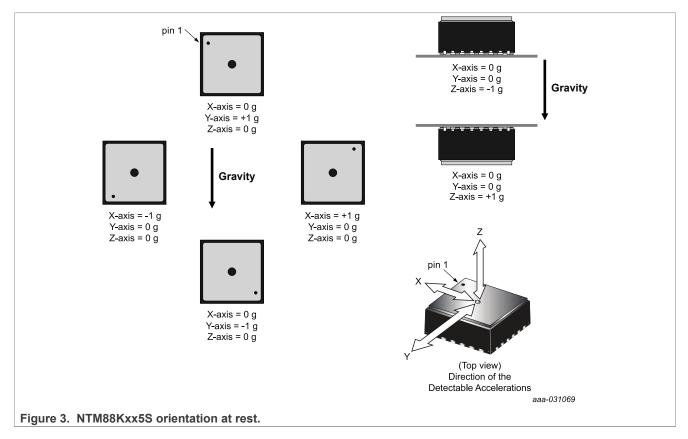
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Symbol	Pin	Function	Description
			"floating" inputs. PTA[1] maps to keyboard interrupt function bit [1]. When SPI is enabled, PTA[1] serves as SCLK
RFGND	17	RF ground	Power in the RF output amplifier is returned to the supply through the RFGND pin. This conductor should be connected to the power supply using a "star" connection such that each metal trace does not share any load currents with other supply pins.
RFOUT	18	RF output	The RFOUT pin is the RF energy data supplied by the unit to an external antenna.
ΡΤΑΟ	19	PTA0 / KBI0 / SS_B / IRQ	The PTA[0] pin is a general-purpose I/O pin. PTA[0] can be configured as a normal bidirectional I/O pin with programmable pullup or pulldown devices and/or wake-up interrupt capability. PTA[0] can be configured for external interrupt (IRQ). The pulldown devices can only be activated if the wake-up interrupt capability is enabled. User software must configure the general-purpose I/O pins so that they do not result in "floating" inputs. PTA[0] maps to keyboard interrupt function bit [0]. When SPI is enabled, PTA0 serves as SS_B.
X1	20	RF crystal input	The X1 pin is for an external 26 MHz crystal to be used by the internal PLL for creating the carrier frequencies and data rates for the RF pin.
X0	21	RF crystal output	The X0 pin is for an external 26 MHz crystal to be used by the internal PLL for creating the carrier frequencies and data rates for the RF pin.
PTB1	22	PTB1 / TPMCH1 / AD4	The PTB[1] pin is a general-purpose I/O pin. This pin can be configured as a nominal bidirectional I/O pin with programmable pullup devices. User software must configure the general-purpose I/O pins (PTB[1:0]) so that they do not result in "floating" inputs. PTB1 can be mapped to TPM channel 1, or to ADC channel 4.
LFB	23	LF input '-'	The LF[A:B] pins can be used by the LF receiver (LFR) as one differential input channel for sensing low-level signals from an external low frequency (LF) coil. The external LF coil should be connected between the LF[A] and the LF[B] pins. Signaling into the LFR pins can place the unit into various diagnostic or operational modes. The LFR is comprised of the detector and the decoder. Each LF[A:B] pin always has an impedance of approximately 500 k $\Omega$ to GND due to the LFR input circuitry. The LFA/LFB pins are used by the LFR when the LFEN control bit is set and are not functional when the LFEN control bit is clear.
LFA	24	LF input '+'	The LF[A:B] pins can be used by the LF receiver (LFR) as one differential input channel for sensing low-level signals from an external low frequency (LF) coil. The external LF coil should be connected between the LF[A] and the LF[B] pins. Signaling into the LFR pins can place the unit into various diagnostic or operational modes. The LFR is comprised of the detector and the decoder. Each LF[A:B] pin always has an impedance of approximately 500 k $\Omega$ to GND due to the LFR input circuitry. The LFA/LFB pins are used by the LFR when the LFEN control bit is set and are not functional when the LFEN control bit is clear.

Table 3. Pin description...continued

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### 5.3 Orientation



## 6 Electrical specifications

Tables in the electrical and mechanical specification sections of this data sheet may contain hyperlinked note references in the last cell of the row. The hyperlinks are linked to and defined in <u>Table 4</u>.

Note identifier	Description
A	Parameters tested 100 % at final test.
В	Parameters tested 100 % at unit probe.
C	Verified by characterization, not tested in production.
D	For information only, may be determined by simulation.

Table 4. Electrical and mechanical specification note definition table

## 6.1 Maximum ratings (electrical)

Maximum ratings are the extreme limits the device can be exposed to without permanently damaging it. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than the values shown in <u>Table 5</u>. Keep  $V_{IN}$  and  $V_{OUT}$  within the range  $V_{SS} \le (V_{IN} \text{ or } V_{OUT}) \le V_{DD}$ .

In all cases of transient environment, the sensor functional behaviors, parametric behaviors, and dimensions may deviate from the listed steady-state environment tolerances as compared to external reference(s).  $\tau$  is the characteristic thermal time constant, from device case ambient to the on-die temperature transducer. Transient

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environment means less than  $2.3 \times \tau$  seconds since the last step-function transient of a condition; pressure, motion, temperature, supply voltage, electro-magnetic, humidity, vapor, media. Steady-state environment means  $2.3 \times \tau$  or more seconds of stable conditions; pressure, motion, temperature, supply voltage, electro-magnetic, humidity, vapor, media. Examples of step-function transient condition might be tire blow-out, drop impact, ice-bath submersion, battery connection 'bounce', nearby radio transmitter, and so forth.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
V <sub>DD</sub>	V <sub>DD</sub> or V <sub>DDA</sub> to V <sub>SS</sub>	$T_L \le T_A \le T_h$	-0.3	_	3.6	V	<u>C</u>
V <sub>IO</sub>	IO pin current, each pin vs V_{DD} / V_{DDA} or V_{SS}	$T_{AS}$ Min $\leq T_A \leq T_A$ Max	V <sub>SS</sub> – 0.3		V <sub>DD</sub> + 0.3	V	<u>C</u>
I <sub>IO</sub>	IO pin current, pin vs $V_{DD}$ / $V_{DDA}$ or $V_{SS}$	$T_L \le T_A \le T_H$ , $V_{DDR}$ Min $\le V_{DD} \le V_{DDR}$ Max	-10		10	mA	<u>C</u>
I <sub>SUBIO</sub>	Substrate current injection, all IO pins except LFA LFB current from pin to $V_{SS} - 0.3 \ V$	$T_L \le T_A \le T_H, V_{DDR} Min \le V_{DD} \le V_{DDR} Max$	_	600	-	μA	<u>C</u>
I <sub>SUBLF</sub>	Substrate current injection, LFA LFB current from pin to $V_{SS} - 0.3$ V	$T_L \le T_A \le T_H, V_{DDF} Min \le V_{DD} \le V_{DDF} Max$	-	2	_	mA	<u>C</u>
ILATCH	Latch-up current, current to/from pin to $V_{DD}$ / $V_{DDA}$ + 0.3 V	$T_L \le T_A \le T_H, V_{DDR} Min \le V_{DD} \le V_{DDR} Max$	-100	_	100	mA	<u>C</u>
ESD <sub>HBM</sub>	Electrostatic discharge, human body model (HBM), all pins except RF, and LF	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V	-2000	_	2000	V	<u>C</u>
ESD <sub>HBM</sub>	Electrostatic discharge, human body model (HBM), RF, and LF	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V	-2000	_	2000	V	<u>C</u>
ESD <sub>CDM</sub>	Electrostatic discharge, charged device model (CDM), all pins	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V	-500		500	V	<u>C</u>
T <sub>STG</sub>	Unpowered storage, temperature range	_	-50	_	150	°C	<u>C</u>

## 6.2 Operating conditions

The limits normally expected in the application that define the range of operation.

Table	6.	Operating	range
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
V <sub>DDR</sub>	Operating voltage range, Parameter register retention where Min = $V_L$ , Typ = 3.0 V, Max = $V_H$	$T_{AS}$ Min $\leq T_A \leq T_{AS}$ Max	1.2	3.0	3.6	V	<u>C</u>
V <sub>DDS</sub>	Operating voltage range, MCU and SW, Flash Read, RF TX, Voltage Measurement where Min = $V_L$ , Typ = 3.0 V, Max = $V_H$	$T_{AS}$ Min $\leq T_A \leq T_{AS}$ Max	V <sub>LVDRF</sub>	3.0	3.6	V	C
V <sub>DDM</sub>	Operating voltage range, Pressure, Temperature and Acceleration Measurements where Min = $V_L$ , Typ = 3.0 V, Max = $V_H$	$T_{AS} Min \le T_A \le T_{AS} Max$	2.1	3.0	3.6	V	<u>C</u>
V <sub>DDF</sub>	Operating voltage range, Flash Programming and LF RX, where Min = $V_L$ , Typ = 3.0 V, Max = $V_H$	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	2.1	3.0	3.6	V	<u>C</u>
T <sub>AS</sub>	Operating temperature range, Full functionality except LF RX, and Flash Programming where Min = $T_L$ , Typ = 25 °C, Max = $T_H$	$V_{DDS}$ Min $\leq V_{DD} \leq V_{DDS}$ Max	-40	25	125	°C	<u>C</u>

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
T <sub>AF</sub>	Operating temperature range, Operating voltage range, Full functionality, including LF RX, and Flash programming	$V_{DDF}$ Min $\leq V_{DD} \leq V_{DDF}$ Max	-20	25	85	°C	C
T <sub>A-EXC</sub>	Operating temperature range excursion; 12 excursions of 15 minutes ea. (all Tolerances may be out of spec)	V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max	_	—	150	°C	<u>C</u>
I <sub>DD1</sub>	Supply Current; Stop1 Mode (only LFO, PWU, and param. reg. On)	Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub> Min to Max & V <sub>DDR</sub> Min to Max	-	0.18	18	μA	B
I <sub>DD4</sub>	Supply Current; Stop4 Mode (only MCU, RF, and LF disabled)	Typ = 25 °C, 3.0 V, Max = $T_{AS}$ Min to Max & $V_{DDS}$ Min to Max	-	75	125	μA	<u>B</u>
I <sub>DDLFS</sub>	Supply Current; Standby LF sniff (and Stop1 equivalent)	Typ = 25 °C, 3.0 V, Max = $T_{AF}$ Min to Max & V <sub>DDF</sub> Min to Max	-	4.8	8.1	μA	<u>C</u>
	Supply Current; Standby LF Decoding (and Stop1 equivalent)	Typ = 25 °C, 3.0 V, Max = $T_{AF}$ Min to Max & V <sub>DDF</sub> Min to Max	-	11.3	14.3	μA	<u>C</u>
İ <sub>DDR5K</sub>	Supply Current; MCU Run 500 kHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = $T_{AS}$ Min to Max & V <sub>DDS</sub> Min to Max	-	0.8	1.0	mA	<u>C</u>
I <sub>DDR1M</sub>	Supply Current; MCU Run 1 MHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = $T_{AS}$ Min to Max & V <sub>DDS</sub> Min to Max	-	1.0	1.2	mA	<u>C</u>
I <sub>DDR2M</sub>	Supply Current; MCU Run 2 MHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = $T_{AS}$ Min to Max & $V_{DDS}$ Min to Max	-	1.42	1.6	mA	<u>C</u>
I <sub>DDR4M</sub>	Supply Current; MCU Run 4 MHz (and RF and LF disabled)	Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub> Min to Max & V <sub>DDS</sub> Min to Max	-	2.1	2.5	mA	B
I <sub>DDRFT3</sub>	Supply Current; RF TX 5 dBm, 315 MHz (and Stop1 equivalent)	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V	-	5.7	6.1	mA	<u>B</u>
I <sub>DDRFT4</sub>	Supply Current; RF TX 5 dBm, 434 MHz (and Stop1 equivalent)	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V	-	6.3	6.8	mA	<u>B</u>
I <sub>DDRFTx1</sub>	Supply Current Increase w/ BOOST = 1 RF TX 5 dBm (and Stop1 equivalent)	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 3.0 V	-	-	0.6	mA	<u>C</u>
I <sub>DDIF0</sub>	Supply Current, RF Interframe period, IFPD = 0	Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub> Min to Max & V <sub>DDS</sub> Min to Max	-	610	870	μA	<u>C</u>
I <sub>DDIF1</sub>	Supply Current, RF Interframe period, IFPD = 1	Typ = 25 °C, 3.0 V, Max = T <sub>AS</sub> Min to Max & V <sub>DDS</sub> Min to Max	-	19	36	μA	<u>C</u>
I <sub>DDA</sub> or I <sub>DDP</sub>	Supply Current Peak; Accel. or Pressure Measurements (and Stop4 equivalent)	Typ = 25 °C, 3.0 V, Max = $T_{AS}$ Min to Max & $V_{DDM}$ Min to Max	-	2.8	3.15	mA	<u>C</u>
I <sub>DDV</sub> or I <sub>DDT</sub>	Supply Current Peak; Voltage or Temp. Measurements (and Stop4 equivalent)	Typ = 25 °C, 3.0 V, Max = $T_{AS}$ Min to Max & $V_{DDM}$ Min to Max	-	2.8	3.8	mA	<u>C</u>

Table 6. Operating range...continued

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## 6.3 Charge consumptions

### Table 7. Charge consumptions

#### $T_L \leq T_A \leq T_{H}$ , unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
Q <sub>wake</sub>	Stop1 to run charge consumption, F <sub>bus</sub> set for 4 MHz	$V_{DDM}$ Min $\leq V_{DD} \leq V_{DDM}$ Max	-	0.10	—	μΑ- sec	<u>C</u>
QPA <sub>r512</sub>	Pressure or accelerometer charge consumption; Raw 512 µs settling per sample	V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max	_	0.95	_	μΑ- sec	<u>C</u>
QPA <sub>r2048</sub>	Pressure or accelerometer charge consumption; Raw 2048 µs settling per sample	V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max	_	1.85	_	μΑ- sec	<u>C</u>
QP <sub>c3</sub>	Pressure charge consumption; Compensation third order per sample	$V_{DDM}$ Min $\leq V_{DD} \leq V_{DDM}$ Max	-	1.77		μΑ- sec	D
QA <sub>c2</sub>	Accelerometer charge consumption; Compensation second order per sample	V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max	-	1.95	_	μΑ- sec	<u>D</u>
QVT <sub>r50</sub>	Voltage or temperature charge consumption; Raw 50 µs conversion per sample	V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max	_	0.2	_	µA- sec	<u>C</u>
QVT <sub>c250</sub>	Voltage or temperature charge consumption; Compensation ~0.25 ms per sample	V <sub>DDM</sub> Min ≤ V <sub>DD</sub> ≤ V <sub>DDM</sub> Max	-	0.50	_	μΑ- sec	<u>D</u>

### 6.4 Clocks and thresholds

#### Table 8. Clocks and thresholds

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
f <sub>BUS</sub>	MCU bus frequency multiple of HFO	V <sub>DD</sub> > V <sub>LVDRF</sub>	_	0.5		x HFO	<u>D</u>
f <sub>HF0</sub>	High frequency oscillator, multiple of MFO	V <sub>DD</sub> > V <sub>LVDRF</sub>	-	64		x MFO	D
t <sub>HFOST</sub>	Stabilization time	—	_	300	1000	μs	D
f <sub>MFO</sub>	Medium frequency oscillator	V <sub>DD</sub> > V <sub>LVDRF</sub>	107	125	135	kHz	Α
f <sub>LFO</sub>	Low frequency oscillator	—	504	-	1512	Hz	<u>B</u>
f <sub>LFRO</sub>	LFR Clock (derived from LFRO)	—	120	129	139	kHz	<u>B</u>
t <sub>STOP1</sub>	MCU wake-up time	From Stop1 to 1 <sup>st</sup> instruction, 4 MHz	-	50	70	μs	<u>C</u>
t <sub>STOP4</sub>	MCU wake-up time	From Stop4 to 1 <sup>st</sup> instruction, 4 MHz	-	25	35	μs	<u>C</u>
t <sub>LV</sub>	Low voltage times	V <sub>DD</sub> < V <sub>LVx</sub>	_	—	10	μs	D
V <sub>LVWLF</sub>	Low voltage warning (LVW)	Lower threshold, V <sub>DD</sub> falling	1.95	-	2.2	V	<u>C</u>
V <sub>LVWLR</sub>	Low voltage warning (LVW)	Lower threshold, V <sub>DD</sub> rising	2.02	-	2.1	V	<u>C</u>
V <sub>LVWHF</sub>	Low voltage warning (LVW)	Higher threshold, V <sub>DD</sub> falling	2.28	-	2.54	V	<u>C</u>
V <sub>LVWHR</sub>	Low voltage warning (LVW)	Higher threshold, V <sub>DD</sub> rising	2.34	-	2.61	V	<u>C</u>
V <sub>LVDLF</sub>	Low voltage detection (LVD)	Lower threshold, V <sub>DD</sub> falling	1.79	-	1.96	V	<u>C</u>
V <sub>LVDLR</sub>	Low voltage detection (LVD)	Lower threshold, V <sub>DD</sub> rising	1.87	-	2.03	V	<u>C</u>

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$V_{DDS}$ Min $\leq V$	$V_{DDS}$ Min $\leq V_{DD} \leq V_{DDS}$ Max, $T_{AS}$ Min $\leq T_A \leq T_{AS}$ Max, unless otherwise specified.									
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit	Notes			
V <sub>LVDHF</sub>	Low voltage detection (LVD)	Higher threshold, V <sub>DD</sub> falling	1.95	—	2.2	V	<u>C</u>			
V <sub>LVDHR</sub>	Low voltage detection (LVD)	Higher threshold, $V_{DD}$ rising	2.02	—	2.1	V	<u>C</u>			
V <sub>LVDRF</sub>	RF LVD	V <sub>DD</sub> falling	1.6	_	2.1	V	<u>C</u>			
T <sub>FDR</sub>	Flash memory data retention	—	10	—	_	Yr	<u>D</u>			

Table 8. Clocks and thresholds...continued

. - *1*1-. . . A A ... .

### 6.5 Power-on reset operation

When power is initially applied to the device, or when the supply voltage drops below the V<sub>POR</sub> level, the POR circuit causes a reset condition. As the supply voltage rises, the LVD circuit holds the chip in reset until the supply has risen above the level determined by LVDV bit. Both the POR bit and the LVD bit in SRS are set following a POR.

#### Table 9. Power-on reset

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
t <sub>R</sub>	Power on reset (POR)	V <sub>DD</sub> risetime to avoid latch up	_	—	1	s	<u>C</u>
t <sub>POR</sub>	Power on reset (POR)	Time for V <sub>DD</sub> < 0.5 V to assure POR	70	—	—	μs	<u>C</u>
V <sub>PORR</sub>	Power on reset (POR)	Rising voltage to release reset	—	—	2.1	V	<u>C</u>
V <sub>PORA</sub>	Power on reset (POR)	Falling voltage to assert reset	0.8	—		V	<u>C</u>

### 6.6 GPIO port pins

#### Table 10. GPIO port pins

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
V <sub>OH</sub>	Output high voltage	I <sub>LOAD</sub> = 5 mA	V <sub>DD</sub> – 0.35	_	_	V	D
V <sub>OL</sub>	Output low voltage	I <sub>LOAD</sub> = 5 mA	_	_	V <sub>SS</sub> + 0.35	V	D
V <sub>IHn</sub>	Input high voltage	$2.3 \text{ V} \le \text{V}_{\text{DD}} \le \text{V}_{\text{H}}, \text{ T}_{\text{A}} = \text{T}_{\text{L}}, \text{T}_{\text{H}}$	0.7 × V <sub>DD</sub> / V <sub>DDA</sub>	_	V <sub>DD</sub> / V <sub>DDA</sub>	V	D
V <sub>IHIv</sub>	Input high voltage	$V_{DD} \le 2.3 \text{ V}, \text{ T}_{A} = 25 \text{ °C}$	0.85 × V <sub>DD</sub> / V <sub>DDA</sub>		V <sub>DD</sub> / V <sub>DDA</sub>	V	<u>D</u>
V <sub>ILn</sub>	Input low voltage	$2.3 \text{ V} \le \text{V}_{\text{DD}} \le \text{V}_{\text{H}}, \text{ T}_{\text{A}} = \text{T}_{\text{L}}, \text{T}_{\text{H}}$	V <sub>SS</sub>		0.35 × V <sub>DD</sub> / V <sub>DDA</sub>	V	<u>D</u>
V <sub>ILIv</sub>	Input low voltage	V <sub>DD</sub> ≤ 2.3 V, T <sub>A</sub> = 25 °C	V <sub>SS</sub>		0.28 × V <sub>DD</sub> / V <sub>DDA</sub>	V	<u>D</u>
I <sub>IH</sub>	Input high current, PTA0:3	Pulldown disabled; V <sub>IH</sub> Min	-1	_	+1	μA	<u>D</u>
I <sub>IHp</sub>	Input high current, PTA0:3	Pulldown enabled; V <sub>IH</sub> Min	0	_	120	μA	<u>D</u>
I <sub>IL</sub>	Input low current, PTA0:3	Pullup disabled; V <sub>IL</sub> Max	-1	—	+1	μA	D
I <sub>ILp</sub>	Input low current, PTA0:3	Pullup enabled; V <sub>IL</sub> Max	-120	_	0	μA	D
I <sub>IH-IL</sub>	Input current PTA4 only	$V_{\rm IH}$ Min and $V_{\rm IL}$ Max	-120	_	120	μA	<u>D</u>

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#### Table 10. GPIO port pins...continued

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
C <sub>IO</sub>	Pin capacitance	V <sub>DD</sub> = 3.0 V	0	—	15	pF	<u>D</u>
C <sub>MISO</sub>	MISO load capacitance	V <sub>DD</sub> = 3.0 V	—	—	50	pF	<u>D</u>

### 6.7 SPI timing characteristics

#### Table 11. SPI timing

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
t <sub>SSMIN</sub>	SS_B asserted period	-	1	_		f <sub>BUS</sub> period	<u>D</u>
t <sub>ACCESS</sub>	SS_B low to MISO	—	—	—	50	ns	D
t <sub>LEAD</sub>	SS_B low to SCLK start	—	50	-	_	ns	D
t <sub>SETUP</sub>	MOSI to SCLK start	—	20	-	_	ns	D
t <sub>SCLK</sub>	SCLK period	—	100	-	_	ns	D
t <sub>SCLKH</sub>	SCLK high portion	—	35	-	_	ns	D
t <sub>SCLKL</sub>	SCLK low portion	—	35	—	_	ns	D
t <sub>SCLKR</sub>	SCLK risetime	—	_	10	25	ns	D
t <sub>SCLKF</sub>	SCLK fall time	—	_	10	25	ns	D
t <sub>VALID</sub>	MISO valid transition time	—	_	—	30	ns	D
t <sub>HOLD_IN</sub>	MOSI hold time	—	10	—	_	ns	D
t <sub>HOLD_OUT</sub>	SCLK high to MISO transition start	—	0	-	_	ns	D
t <sub>LAG</sub>	Final SCLK low to SS_B high	—	60	—	_	ns	D
t <sub>DISABLE</sub>	SS_B high to MISO 3-state	—	_	-	60	ns	D
t <sub>SS_REJ</sub>	SS_B noise rejection period	—	_	—	5	ns	D
t <sub>SSCLK</sub>	SS_B high to SCLK high	—	50	—	_	ns	D
t <sub>CLKSS</sub>	SCLK high to SCLK low	—	50	—	_	ns	D
t <sub>SSN</sub>	SS_B not asserted period	-	6	_		f <sub>BUS</sub> period	<u>D</u>
t <sub>LEAD-WU</sub>	Wake-up by SS_B low to SCLK start	—	1	—	—	ms	D
t <sub>SPI_EN</sub>	SPI enable by SS_B low after V <sub>DD</sub> > V <sub>PORR</sub>	-	200	_	_	μs	D

### 6.8 Temperature measurement characteristics

#### Table 12. Temperature measurement

 $V_{DDM} Min \le V_{DD} \le V_{DDM} Max$ ,  $T_{AS} Min \le T_A \le T_{AS} Max$ , unless otherwise specified. Transfer function:  $T \ ^{\circ}C = (1 \ ^{\circ}C / LSB \times T_{CODE}) - 55 \ ^{\circ}C$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
DT <sub>MAX-MIN</sub>	Sensitivity	—	0.93	1	1.08	°C / LSB	<u>C</u>
T <sub>ERROR</sub>	Error	—	_	0	_	LSB	<u>C</u>
T <sub>UNDER</sub>	Underflow	—	_	1	_	LSB	<u>C</u>

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
T <sub>OVER</sub>	Overflow	—		255		LSB	<u>C</u>
T <sub>MIN</sub>	Temperature measurement	T <sub>A</sub> = -50 °C		5	_	LSB	D
T <sub>RATE-MIN</sub>	Temperature measurement	T <sub>A</sub> = -40 °C	11	15	19	LSB	<u>C</u>
T <sub>CODE</sub>	Temperature measurement	T <sub>A</sub> = -20 °C	32	35	38	LSB	A
T <sub>CODE</sub>	Temperature measurement	T <sub>A</sub> = 0 °C	52	55	58	LSB	<u>C</u>
T <sub>CODE</sub>	Temperature measurement	T <sub>A</sub> = 25 °C	77	80	83	LSB	B
T <sub>CODE</sub>	Temperature measurement	T <sub>A</sub> = 70 °C	122	125	128	LSB	<u>C</u>
T <sub>CODE</sub>	Temperature measurement	T <sub>A</sub> = 85 °C	137	140	143	LSB	Α
T <sub>CODE</sub>	Temperature measurement	T <sub>A</sub> = 105 °C	156	160	164	LSB	<u>C</u>
T <sub>RATE-MAX</sub>	Temperature measurement	T <sub>A</sub> = 125 °C	175	180	185	LSB	B
T <sub>MAX</sub>	Temperature measurement	T <sub>A</sub> = 150 °C <sup>[1]</sup>		205	_	LSB	D
T <sub>STAB</sub>	Temperature measurement stability range	_	-3	_	+3	LSB	<u>C</u>

Table 12. Temperature measurement...continued

[1] Temperature excursions, time at T<sub>MAX</sub> must not exceed 12 events of 15 minutes duration during the product lifetime.

### 6.9 Voltage measurement characteristics

#### Table 13. Voltage measurement characteristics

 $V_{DDS} Min \le V_{DD} \le V_{DDS} Max$ ,  $T_{AS} Min \le T_A \le T_{AS} Max$ , unless otherwise specified. Transfer function:  $V = (0.01 V / LSB \times V_{CODE}) + 1.22 V$ Interpolated limits between -40 °C to 0 °C and between 50 °C to 125 °C.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit	Notes
DV <sub>MAX-MIN</sub>	Sensitivity	-	9	10	12	mV / LSB	<u>C</u>
V <sub>ERROR</sub>	Error	-	_	0	_	LSB	<u>C</u>
V <sub>UNDER</sub>	Underflow	—	_	1	_	LSB	<u>C</u>
V <sub>OVER</sub>	Overflow	—		255	_	LSB	<u>C</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 2.8 V	$0 \text{ °C} \le T_A \le 50 \text{ °C}, V_{DD} = 2.8 \text{ V}$	153	158	163	LSB	<u>C</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 3.0 V	$0 \text{ °C} \le T_A \le 50 \text{ °C}, V_{DD} = 3.0 \text{ V}$	173	178	183	LSB	<u>C</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 3.3 V	$0 \text{ °C} \le T_A \le 50 \text{ °C}, V_{DD} = 3.3 \text{ V}$	203	208	213	LSB	<u>C</u>
V <sub>MIN</sub>	V <sub>DD</sub> voltage, 1.8 V	-	38	58	78	LSB	<u>C</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 2.1 V	—	68	88	108	LSB	<u>B</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 2.3 V	$\begin{array}{l} -40 \ ^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 0 \ ^{\circ}\text{C} \text{ or } 50 \ ^{\circ}\text{C} \leq \text{T}_{\text{A}} \\ \leq 125 \ ^{\circ}\text{C}, \ \text{V}_{\text{DD}} = 2.3 \ \text{V} \end{array}$	98	108	118	LSB	<u>C</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 2.8 V	$\begin{array}{l} -40 \ ^\circ\text{C} \leq \text{T}_{\text{A}} \leq 0 \ ^\circ\text{C} \text{ or } 50 \ ^\circ\text{C} \leq \text{T}_{\text{A}} \\ \leq 125 \ ^\circ\text{C}, \ \text{V}_{\text{DD}} = 2.8 \ \text{V} \end{array}$	148	158	168	LSB	<u>C</u>
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 3.0 V	$\begin{array}{l} -40 \ ^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 0 \ ^{\circ}\text{C} \text{ or } 50 \ ^{\circ}\text{C} \leq \text{T}_{\text{A}} \\ \leq 125 \ ^{\circ}\text{C}, \ \text{V}_{\text{DD}} = 3.0 \ \text{V} \end{array}$	168	178	188	LSB	B
V <sub>CODE</sub>	V <sub>DD</sub> voltage, 3.3 V	-40 °C ≤ T <sub>A</sub> ≤ 0 °C or 50 °C ≤ T <sub>A</sub> ≤ 125 °C, V <sub>DD</sub> = 3.3 V	198	208	218	LSB	<u>C</u>
V <sub>MAX</sub>	V <sub>DD</sub> voltage, 3.6 V	-	228	238	248	LSB	<u>C</u>
V <sub>STAB</sub>	Voltage measurement stability range	—	-3	-	+3	LSB	<u>C</u>

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#### Table 14. External pin voltage measurement

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified. Transfer function:  $V = (V_{DD} V / LSB \times GxCODE) / 1023$ , where x = 0 for PTB0, 1 for PTB1

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
∆GxMAX- MIN	Sensitivity	_	_	V <sub>DD</sub> / 1023	_	V / LSB	<u>C</u>
GxERROR	Error	Status = \$01	_	0	_	LSB	<u>C</u>
GxCODE	Voltage measurement, V = 0 V	Status = \$00		0		LSB	<u>C</u>
GxCODE	Voltage measurement, V = VDD V	—	_	1023	_	LSB	<u>C</u>
GxSTAB	Voltage measurement stability range	—	-1	—	+1	LSB	<u>C</u>

#### 6.10 Pressure measurement characteristics

Unless otherwise noted, stated tolerances are valid only with Initial Sample Delay [ISD3:0] set for > 2.5 ms and MCU placed in STOP4 mode.

#### 6.10.1 Pressure measurement characteristic (90 kPa to 1518 kPa range)

### Table 15. Pressure measurement characteristics (90 kPa to 1518 kPa range)

 $V_{DDM}$   $Min \le V_{DD} \le V_{DDM}$  Max,  $T_{AS}$   $Min \le T_A \le T_{AS}$  Max, unless otherwise specified. Transfer function:  $P \ kPa = (1.4 \ kPa \ / LSB \times P_{CODE}) + 87.2 \ kPa$ 

Interpolated limits between 105 °C and 125 °C.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit	Notes
DP <sub>MAX-MIN</sub>	Sensitivity	-	1.35	1.4	1.43	kPa / LSB	<u>C</u>
P <sub>ERROR</sub>	Error		_	0	_	LSB	<u>C</u>
P <sub>UNDER</sub>	Underflow	FW error status bit 0 = 1	_	1	—	LSB	<u>C</u>
P <sub>OVER</sub>	Overflow	FW error status bit 0 = 1	_	1023	_	LSB	<u>C</u>
P <sub>MIN</sub>	Proof pressure, 90 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	_	2	14	LSB	D
P <sub>CODE</sub>	Proof pressure, 100 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	_	9	21	LSB	Α
P <sub>CODE</sub>	Proof pressure, 328 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	160	172	184	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 350 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	176	188	200	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 566 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	330	342	354	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 804 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	500	512	524	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 1042 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	670	682	694	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 1050 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	676	688	700	LSB	A
P <sub>CODE</sub>	Proof pressure, 1280 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	840	852	864	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 1500 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	998	1010	1022	LSB	A
P <sub>MAX</sub>	Proof pressure, 1518 kPa	–40 °C ≤ T <sub>A</sub> ≤ 105 °C	1010	1022	_	LSB	D
P <sub>MIN</sub>	Proof pressure, 90 kPa	T <sub>A</sub> = 125 °C	_	2	28	LSB	<u>D</u>
P <sub>CODE</sub>	Proof pressure, 100 kPa	T <sub>A</sub> = 125 °C	_	9	35	LSB	Α
P <sub>CODE</sub>	Proof pressure, 328 kPa	T <sub>A</sub> = 125 °C	146	172	198	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 350 kPa	T <sub>A</sub> = 125 °C	162	188	214	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 566 kPa	T <sub>A</sub> = 125 °C	316	342	368	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 804 kPa	T <sub>A</sub> = 125 °C	486	512	538	LSB	<u>C</u>
P <sub>CODE</sub>	Proof pressure, 1042 kPa	T <sub>A</sub> = 125 °C	656	682	708	LSB	<u>C</u>
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## **Table 15. Pressure measurement characteristics (90 kPa to 1518 kPa range)**...continued $V_{DDM}$ Min $\leq V_{DD} \leq V_{DDM}$ Max, $T_{AS}$ Min $\leq T_A \leq T_{AS}$ Max, unless otherwise specified. Transfer function: P kPa = (1.4 kPa / LSB × P<sub>CODE</sub>) + 87.2 kPa Interpolated limits between 105 °C and 125 °C.

Symbol Parameter Conditions Notes Min Тур Max Unit Proof pressure, 1050 kPa T<sub>A</sub> = 125 °C 688 714 LSB P<sub>CODE</sub> 662 Α Proof pressure, 1280 kPa T<sub>A</sub> = 125 °C 826 852 878 LSB С P<sub>CODE</sub> Proof pressure, 1500 kPa T<sub>A</sub> = 125 °C 984 1010 1036 LSB P<sub>CODE</sub> A Proof pressure, 1518 kPa T<sub>A</sub> = 125 °C 996 1022 LSB D P<sub>MAX</sub>

### 6.11 Acceleration measurement characteristics

Unless otherwise noted, stated tolerances are valid only with Initial Sample Delay [ISD3:0] set for > 2.5 ms and MCU placed in STOP4 mode.

### 6.11.1 Acceleration measurement characteristics (-80 g to +90 g) range option

**Table 16.** Acceleration measurement characteristic (-80 g to +90 g) range option  $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified. Transfer Function: Offset Step 7 A g's = (0.020 g/LSB × A<sub>CODE</sub>) – 10.039 g Interpolated limits between -40 °C to -20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
DA <sub>MAX-MIN</sub>	Sensitivity	-	0.014	0.020	0.034	g / LSB	<u>C</u>
A <sub>ERROR</sub>	Error	—	_	0		LSB	<u>C</u>
A <sub>UNDER</sub>	Underflow	FW error status bit 0 = 1	_	1		LSB	<u>C</u>
A <sub>OVER</sub>	Overflow	FW error status bit 0 = 1	_	1023		LSB	<u>C</u>
A <sub>MIN0</sub>	Acceleration measurement, –80 g, Offset step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	-	2	—	LSB	D
A <sub>CODE0</sub>	Acceleration measurement, –75 g, Offset Step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	257	_	LSB	<u>D</u>
A <sub>CODE0</sub>	Acceleration measurement, –70 g, Offset Step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	512	_	LSB	<u>D</u>
A <sub>CODE0</sub>	Acceleration measurement, –65 g, Offset Step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	767	—	LSB	D
A <sub>MAX0</sub>	Acceleration measurement, –60 g, Offset Step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	1022	_	LSB	D
A <sub>MIN7</sub>	Acceleration measurement, -10 g, Offset Step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	2	180	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, –5 g, Offset Step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	104	257	410	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, 0 g, Offset Step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	384	512	640	LSB	A
A <sub>CODE7</sub>	Acceleration measurement, 5 g, Offset Step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	614	767	920	LSB	D
A <sub>MAX7</sub>	Acceleration measurement, 10 g, Offset Step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	844	1022	_	LSB	D
A <sub>MIN7</sub>	Acceleration measurement, -10 g, Offset Step 7	T <sub>A</sub> = –40 °C and 125 °C	-	2	216	LSB	D

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## **Table 16.** Acceleration measurement characteristic (-80 g to +90 g) range option...continued $V_{DDS}$ Min $\leq V_{DD} \leq V_{DDS}$ Max, $T_{AS}$ Min $\leq T_A \leq T_{AS}$ Max, unless otherwise specified. Transfer Function: Offset Step 7 A g's = (0.020 g/LSB × A<sub>CODE</sub>) - 10.039 g

Interpolated limits between -40 °C to -20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
A <sub>CODE7</sub>	Acceleration measurement, –5 g, Offset Step 7	$T_A = -40$ °C and 125 °C	73	257	441	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, 0 g, Offset Step 7	$T_A = -40$ °C and 125 °C	359	512	665	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, 5 g, Offset Step 7	$T_A = -40$ °C and 125 °C	583	767	951	LSB	D
A <sub>MAX7</sub>	Acceleration measurement, 10 g, Offset Step 7	$T_A = -40$ °C and 125 °C	808	1022	—	LSB	D
A <sub>MIN15</sub>	Acceleration measurement, 70 g, Offset Step 15	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	2	_	LSB	<u>D</u>
A <sub>CODE15</sub>	Acceleration measurement, 75 g, Offset Step 15	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	257	—	LSB	<u>D</u>
A <sub>CODE15</sub>	Acceleration measurement, 80 g, Offset Step 15	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	512	_	LSB	<u>D</u>
A <sub>CODE15</sub>	Acceleration measurement, 85 g, Offset Step 15	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	767	_	LSB	D
A <sub>MAX15</sub>	Acceleration measurement, 90 g, Offset Step 15	$-20 \text{ °C} \le T_A \le 85 \text{ °C}$	_	1022	_	LSB	<u>D</u>
A <sub>STAB</sub>	Acceleration measurement stability range	_	-5	-	+5	LSB	<u>C</u>

### 6.11.2 Acceleration measurement characteristic (-360 g to +400 g) range option

#### Table 17. Acceleration measurement characteristic (-360 g to +400 g) range option

 $V_{DDM}$  Min  $\leq V_{DD} \leq V_{DDM}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified. Transfer Function: Offset Step 7 A g's = (0.088 g/LSB × A<sub>CODE</sub>) – 45.176 g Interpolated limits between –40 °C to –20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
DdrA <sub>MAX-</sub> MIN	Sensitivity	_	0.074	0.088	0.108	g / LSB	<u>C</u>
A <sub>ERROR</sub>	Error	—	_	0	—	LSB	<u>C</u>
A <sub>UNDER</sub>	Underflow	FW error status bit 0 = 1	_	1	_	LSB	<u>C</u>
A <sub>OVER</sub>	Overflow	FW error status bit 0 = 1	_	1023	_	LSB	<u>C</u>
A <sub>MIN0</sub>	Acceleration measurement, –360 g, Offset step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	2	_	LSB	D
A <sub>CODE0</sub>	Acceleration measurement, –338 g, Offset step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	257	_	LSB	D
A <sub>CODE0</sub>	Acceleration measurement, –315 g, Offset step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	512		LSB	D
A <sub>CODE0</sub>	Acceleration measurement, –293 g, Offset step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	767		LSB	<u>D</u>
A <sub>MAX0</sub>	Acceleration measurement, –270 g, Offset step 0	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	1022		LSB	<u>D</u>
A <sub>MIN7</sub>	Acceleration measurement, -45 g, Offset step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	2	81	LSB	<u>D</u>

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## **Table 17.** Acceleration measurement characteristic (-360 g to +400 g) range option...continued $V_{DDM}$ Min $\leq V_{DD} \leq V_{DDM}$ Max, $T_{AS}$ Min $\leq T_A \leq T_{AS}$ Max, unless otherwise specified. Transfer Function: Offset Step 7 A g's = (0.088 g/LSB × A<sub>CODE</sub>) - 45.176 g Interpolated limits between -40 °C to -20 °C and between 85 °C to 125 °C

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
A <sub>CODE7</sub>	Acceleration measurement, -22.5 g, Offset step 7	-20 °C ≤ T <sub>A</sub> ≤ 85 °C	203	257	311	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, 0 g, Offset step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	483	512	541	LSB	A
A <sub>CODE7</sub>	Acceleration measurement, 22.5 g, Offset step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	713	767	821	LSB	D
A <sub>MAX7</sub>	Acceleration measurement, 45 g, Offset step 7	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	943	1022		LSB	D
A <sub>MIN7</sub>	Acceleration measurement, -45 g, Offset step 7	T <sub>A</sub> = –40 °C and 125 °C	_	2	97	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, -22.5 g, Offset step 7	T <sub>A</sub> = –40 °C and 125 °C	192	257	322	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, 0 g, Offset step 7	T <sub>A</sub> = –40 °C and 125 °C	478	512	546	LSB	D
A <sub>CODE7</sub>	Acceleration measurement, 22.5 g, Offset step 7	$T_A = -40$ °C and 125 °C	702	767	832	LSB	D
A <sub>MAX7</sub>	Acceleration measurement, 45 g, Offset step 7	T <sub>A</sub> = –40 °C and 125 °C	927	1022		LSB	D
A <sub>MIN15</sub>	Acceleration measurement, 315 g, Offset Step 15	-20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	2		LSB	<u>D</u>
A <sub>CODE15</sub>	Acceleration measurement, 338 g, Offset Step 15	-20 °C ≤ T <sub>A</sub> ≤ 85 °C	-	257		LSB	<u>D</u>
A <sub>CODE15</sub>	Acceleration measurement, 360 g, Offset Step 15	-20 °C ≤ T <sub>A</sub> ≤ 85 °C	-	512		LSB	<u>D</u>
A <sub>CODE15</sub>	Acceleration measurement, 383 g, Offset Step 15	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	-	767	—	LSB	<u>D</u>
A <sub>MAX15</sub>	Acceleration measurement, 405 g, Offset Step 15	–20 °C ≤ T <sub>A</sub> ≤ 85 °C	_	1022	_	LSB	D
A <sub>STAB</sub>	Acceleration measurement stability range	-	-4	-	+4	LSB	<u>C</u>

### 6.12 Low frequency receiver characteristics

#### Table 18. LFR characteristics

 $V_{DDF}$  Min  $\leq V_{DD} \leq V_{DDF}$  Max,  $T_{AF}$  Min  $\leq T_A \leq T_{AF}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
R <sub>LFDF</sub>	LFA / LFB load resistance	—	0.8	_	4	MΩ	D
DR <sub>LFIN</sub>	Dynamic range, f <sub>C</sub> at BW <sub>ACC</sub>	Data mode, always detect	56	_	—	dB	D
V <sub>IN-AD-H</sub>	Sensitivity, high - carrier and data modes	Always detect	_	—	3.0	mVPP	<u>B</u>
V <sub>IN-ND-H</sub>	Sensitivity, high - carrier and data modes	Never detect	0.25	—		mVPP	<u>B</u>
V <sub>IN-AD-L</sub>	Sensitivity, low - carrier and data modes	Always detect	_	_	12.0	mVPP	<u>B</u>

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#### Table 18. LFR characteristics...continued

 $V_{DDF}$  Min  $\leq V_{DD} \leq V_{DDF}$  Max,  $T_{AF}$  Min  $\leq T_A \leq T_{AF}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
V <sub>IN-ND-L</sub>	Sensitivity, low - carrier and data modes	Never detect	4.0	—	_	mVPP	B
MD	Modulation depth	—	70	_	100	%	<u>C</u>
BRLF	Baud rate	—	3788	3906	4032	Bit/s	<u>C</u>
DCM	Manchester duty cycle tolerance	-	-	40 / 60	45 / 55	%	<u>C</u>
DCN	NRZ duty cycle tolerance	-	-	50 / 50	45 / 55	%	<u>C</u>
MER	Message error rate	—	_	5	_	%	<u>C</u>
BW <sub>ACC</sub>	Bandwidth	Always detect	≥ 88	-	≤ 175	kHz	<u>C</u>
BW <sub>REJ</sub>	Bandwidth	Never detect	< 88	_	> 175	kHz	<u>C</u>
t <sub>LF</sub>	Signal rise / decay time constant, carrier envelope	-	15.3	_	_	μs	D

### 6.13 Radio frequency transmitter characteristics

#### Table 19. Radio frequency transmitter characteristics

 $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified. All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
PRF3	Nominal output power with 50 $\Omega$ matching network <sup>[1]</sup>	315 MHz, 25 °C, 3.0 V PWR[4:0] = 0 1 1 0 0	_	5	_	dBm	<u>C</u>
PRF4	Nominal output power with 50 $\Omega$ matching network <sup>[1]</sup>	434 MHz, 25 °C, 3.0 V PWR[4:0] = 0 1 1 1 0	_	5	_	dBm	<u>C</u>
PRF	Output power, range		-1.5	—	8	dBm	<u>C</u>
PRFSTEP	Output power, step size	_	—	0.5	—	dBm	<u>C</u>
PRFMINp	Output power, minimum PRF vs. T <sub>A</sub> and V <sub>DD</sub> under control of FW TPMS_ RF_DYNAMIC_POWER	-40 °C ≤ TA ≤ 0 °C and 1.8 V ≤ V <sub>DD</sub> ≤ 2.5 V, or 0 °C ≤ T <sub>A</sub> ≤ 125 °C and 2.5 V ≤ V <sub>DD</sub> ≤ 3.6 V	3	_		dBm	<u>C</u>
PRFMINn	Output power, minimum PRF vs. T <sub>A</sub> and V <sub>DD</sub> under control of FW TPMS_ RF_DYNAMIC_POWER	25 °C $\leq$ T <sub>A</sub> $\leq$ 60 °C and 2.5 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V	5	_	_	dBm	<u>C</u>
PRFMIN00	Output power, Step = 00		—	-10	_	dBm	<u>C</u>
FSK	Frequency shift key step	_	—	3.17	_	kHz	<u>D</u>
MOOK	On off key modulation depth		60	80	_	dBc	<u>C</u>
BRRF	Baud rate range	_	1.2	-	38.4	kbits/ sec	<u>C</u>
DR	Manchester encoding bit/s accuracy, based on MFO	_	-5	-	+5	%	D
DC	Modulation duty cycle, FSK, and OOK		45	50	55	%	<u>C</u>
FxTAL	External crystal frequency, all conditions	_	_	26	—	MHz	D
t <sub>s-RCTS</sub>	Fixed portion, RF start-up process	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	—	500	620	μs	<u>C</u>

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**Table 19. Radio frequency transmitter characteristics**...continued $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
Bits	Variable portion, RF start-up process	_	-	3	—	bit times	<u>C</u>
tRF2	Total RF start time, write of SEND bit to start of RF output, at 2000 bit/s, where tRF = tS-RCTS + (Bits * bit/s^– 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	_	2	2.2	ms	<u>C</u>
tRF9	Total RF start time, write of SEND bit to start of RF output, at 9600 bit/s, where tRF = tS-RCTS + (Bits * bit/s^– 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	_	800	920	μs	<u>C</u>
tRF20	Total RF start time, write of SEND bit to start of RF output, at 2000 bit/s, where tRF = tS-RCTS + (Bits * bit/s^– 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	_	640	760	μs	<u>C</u>
H2	Harmonic 2, 315 MHz or 434 MHz, with 50 $\Omega$ matching network <sup>[1]</sup> , power step adjusted to reach target power in each domain.	_	-	_	-22	dBc	<u>C</u>
H3	Harmonic 3, 315 MHz or 434 MHz, with 50 $\Omega$ matching network <sup>[1]</sup> , power step adjusted to reach target power in each domain.	_	_	_	-31	dBc	<u>C</u>
H4	Harmonic 4, 315 MHz or 434 MHz, with 50 $\Omega$ matching network <sup>[1]</sup> , power step adjusted to reach target power in each domain.		_	_	-40	dBc	<u>C</u>
N3PH10k	315 MHz phase noise, ±10 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	_	-87	-78	dBc / Hz	<u>C</u>
N3PH100k	315 MHz phase noise, ±100 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-95	-87	dBc / Hz	<u>C</u>
N3PH1M	315 MHz phase noise, ±1 MHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-82	-77	dBc / Hz	<u>C</u>
N31PH10k	315 MHz phase noise, ±10 kHz, Boost = 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-75	-66	dBc / Hz	<u>C</u>
N31PH100k	315 MHz phase noise, ±100 kHz, Boost = 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-83	-75	dBc / Hz	<u>C</u>
N31PH1M	315 MHz phase noise, ±1 MHz, Boost = 1	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-96	-93	dBc / Hz	<u>C</u>
N4PH10k	434 MHz phase noise, ±10 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-85	-75	dBc / Hz	<u>C</u>
N4PH100k	434 MHz phase noise, ±100 kHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-92	-83	dBc / Hz	<u>C</u>
N4PH1M	434 MHz phase noise, ±1 MHz, Boost = 0	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	-	-83	-78	dBc / Hz	<u>C</u>
NPH10M	Phase noise, ±10 MHz	Typ = 25 °C, 3.0 V, Max = TAS Min to Max & VDDS Min to Max	_	-105	-101	dBc / Hz	<u>C</u>
NSP315	Spurious noise, <1 GHz, 10 kHz BW 315 MHz FCC 15.231a–e		_	-	-30	dBc	<u>C</u>
NSPUG	Spurious noise, < 1 GHz, 10 kHz BW 434 MHz ETSI EN300220		_	-	-40	dBc	<u>C</u>

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**Table 19.** Radio frequency transmitter characteristics...continued $V_{DDS}$  Min  $\leq V_{DD} \leq V_{DDS}$  Max,  $T_{AS}$  Min  $\leq T_A \leq T_{AS}$  Max, unless otherwise specified.All conditions characterized with NDK NX2016SA 26.000 MHz crystal.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
NSPOG	Spurious noise, >1 GHz, 10 kHz BW 434 MHz ETSI EN300220	_	—	_	-40	dBc	<u>C</u>
OBWKF	Occupied bandwidth, < ±35 kHz FSK up to 19.2 kbit/s Korea, MIC 2007-63	_	—	_	200	kHz	<u>C</u>
OBWKO	Occupied bandwidth, OOK up to 9.6 kbit/s, Korea, MIC 2007-64	_	—	—	200	kHz	<u>C</u>
OBWJF	Occupied bandwidth, < ±45 kHz FSK up to 38.4 kbit/s, Japan, ARIB STD- T93	_	—	_	400	kHz	<u>C</u>
OBWJO	Occupied bandwidth, OOK up to 19.2 kbit/s, Japan, ARIB STD-T94	—	—	—	600	kHz	<u>C</u>
ML	Oscillation margin	—	850	—		Ω	<u>D</u>
f <sub>XCO</sub>	Internal oscillator accuracy	—	-10	_	+10	ppm	<u>D</u>
VAREGOK	RF $V_{reg}$ capacitor Pre-charge voltage - Note: 0.47 $\mu$ F $V_{reg}$ capacitor connected.	V <sub>DDS</sub> ≥ 2.1 V	_	1.5	_	V	<u>C</u>
t <sub>AREGOK</sub>	$\begin{array}{c} RF \; V_{reg} \; \text{capacitor} \; Pre-charge \; Process \\ \text{-} \; Note: \; 0.47 \; \muF \; V_{reg} \; capacitor \\ \text{connected}, \; additional \; to \; t_{S\text{-RCTS}} \end{array}$	V <sub>DDS</sub> ≥ 2.1 V		630	1000	µSec	<u>D</u>

[1] 50  $\Omega$  is the input impedance of the measurement equipment

The firmware routine TPMS\_PRECHARGE\_EN performs the pre-charge of RF  $V_{reg}$  capacitor. When the precharge is successful, the execution time of the routine corresponds to  $t_{AREGOK}$  duration. When the pre-charge fails, the routine exits after a timeout longer than  $t_{AREGOK}$  max duration.

### 6.14 Power consumption RF transmissions

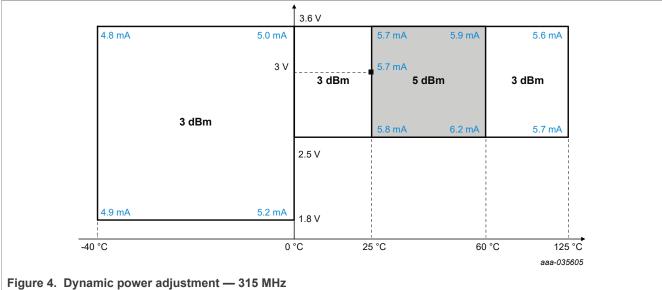
Using the TPMS\_RF\_DYNAMIC\_POWER firmware routine<sup>2</sup> allows adjusting the power step in order to compensate for variations of output power versus temperature and voltage. This routine is associated to a part-to-part trimming that initially adjusts the power step to compensate for process variations.

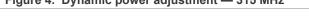
<sup>&</sup>lt;sup>2</sup> Refer to user manual, UM11227.<sup>[1]</sup>

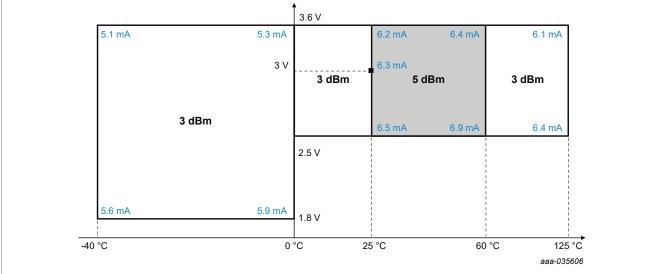
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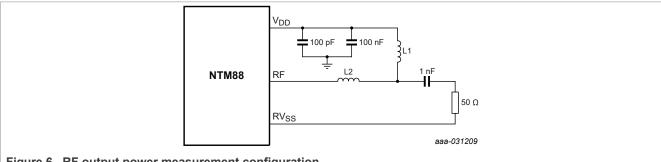
### Tire pressure monitor sensor

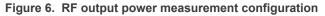




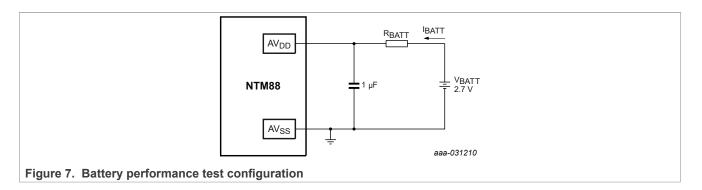


#### Figure 5. Dynamic power adjustment — 434 MHz





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## 7 Mechanical specifications

## 7.1 Maximum ratings (mechanical)

Maximum ratings are the extreme limits the device can be exposed without permanent damage. The device contains circuitry to protect the inputs against damage from high static voltages; however, do not apply voltages higher than the values shown in <u>Table 20</u>. Keep V<sub>IN</sub> and V<sub>OUT</sub> within the range V<sub>SS</sub>  $\leq$  (V<sub>IN</sub> or V<sub>OUT</sub>)  $\leq$  V<sub>DD</sub>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	Notes
P <sub>burst1k</sub>	Pressure transducer, minimum burst pressure	≤ 1518 kPa rating	2000	—	_	kPa	D
f <sub>P0</sub>	Pressure transducer, minimum natural resonance frequency	_	_	5	_	MHz	D
Q <sub>P</sub>	Pressure transducer damping ratio	—	—	1	_	_	D
PA <sub>N</sub>	Pressure transducer, sensitivity to vertical acceleration	–500 g ≤ A ≤ +500 g	_	0	_	Pa/g	<u>C</u>
PA <sub>neg</sub>	Pressure transducer, sensitivity to vertical acceleration	A < -500 g	2	4.5	6.5	Pa/g	<u>C</u>
PA <sub>pos</sub>	Pressure transducer, sensitivity to vertical acceleration	A > +500 g	-6.5	-4.5	-2	Pa/g	<u>C</u>
f <sub>A0</sub>	Accelerometer, minimum natural resonance frequency	_	7	_	16	kHz	D
Q <sub>A</sub>	Accelerometer, damping ratio	—	1	—	4	_	<u>D</u>
AP1k	Accelerometer, sensitivity to pressure	90 kPa ≤ P ≤ 1518 kPa	-1.5	_	+1.5	g / 1000 kPa	<u>C</u>
A <sub>stop2h</sub>	Accelerometer, minimum acceleration to reach travel stop	≤ 100 g rating	-200	—	+200	g	D
A <sub>stop7h</sub>	Accelerometer, minimum acceleration to reach travel stop	> 100 g rating	-700	-	+700	g	<u>D</u>
m	Package Mass	—	—	0.2		gram	<u>D</u>
τ	Thermal time constant	-	_	101		sec	D

#### Table 20. Maximum ratings

## 7.2 Media compatibility

Media compatibility is based on media and test method described in NXP Specification NXPOMS-1719007347-17056.<sup>[2]</sup> Consult your sales representative for more details and specific requirements.

#### Note:

The devices contain a gel that protects the pressure transducer and its inter-die connection wires from corrosion, which might otherwise result in catastrophic failure modes. NXP has observed that direct exposure to materials with the same or nearly-the-same solubility can potentially result in a corruption of the protective gel. A corruption can be less than catastrophic in nature, however may result in an offset of the pressure measurement from its factory calibrated value. An offset can potentially be larger than the allowed tolerances published in this data sheet.

Further, NXP does not recommend direct exposure to strong acid or strong base compounds as they can potentially result in a similar corruption as described above, or may result in a dissolution of the protective gel and/or the metal lid adhesive and/or the plastic device body. Such a dissolution can be catastrophic in nature, damaging the transducer surfaces and/or internal wire bonds and/or the control die surfaces. A potential dissolution may result in a similar offset, or cause the device to indicate overflow/underflow status, or may cause the device to cease operating in the worst case.

For a list of compounds known to generate out-of-tolerance offsets and/or catastrophic device failure, please contact an NXP sales representative.

## 8 Mounting recommendations

The package should be mounted with the pressure port pointing away from the axis of tire rotation. By mounting the pressure port away from the axis of tire rotation, centrifugal force propels any contaminants out of the pressure port. In cases where the application must orient the pressure port pointing inward, care must be taken to assure contaminants do not reach inside the pressure port.

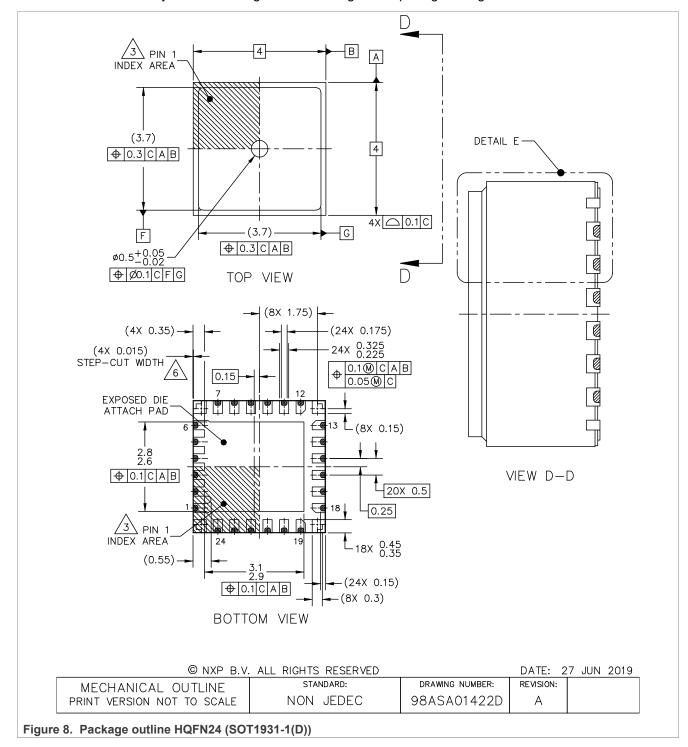
A plugged port exhibits no change in pressure and can be cross checked in the user software. Use the method described in user manual UM11227.<sup>[1]</sup>

Refer to application note AN1902<sup>[3]</sup> for proper printed circuit board attributes and recommendations.

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## 9 Package outline

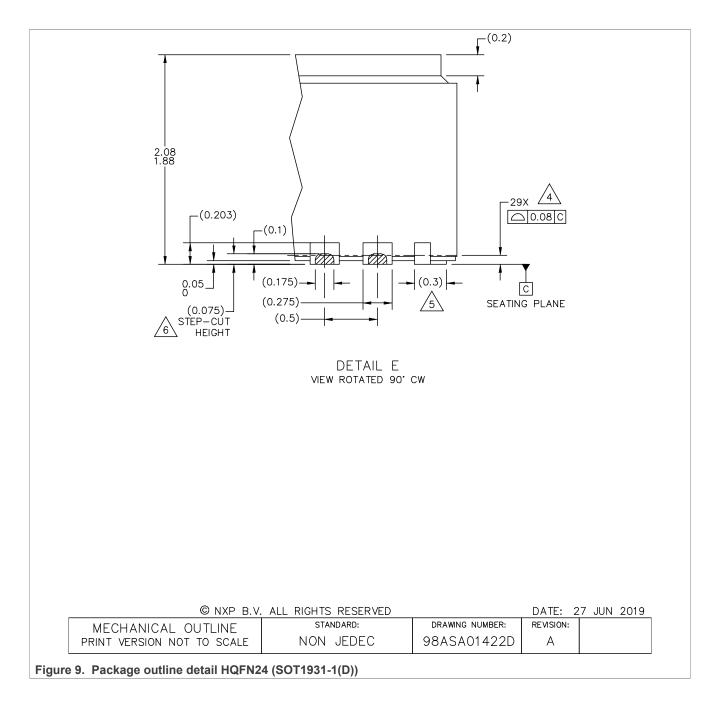


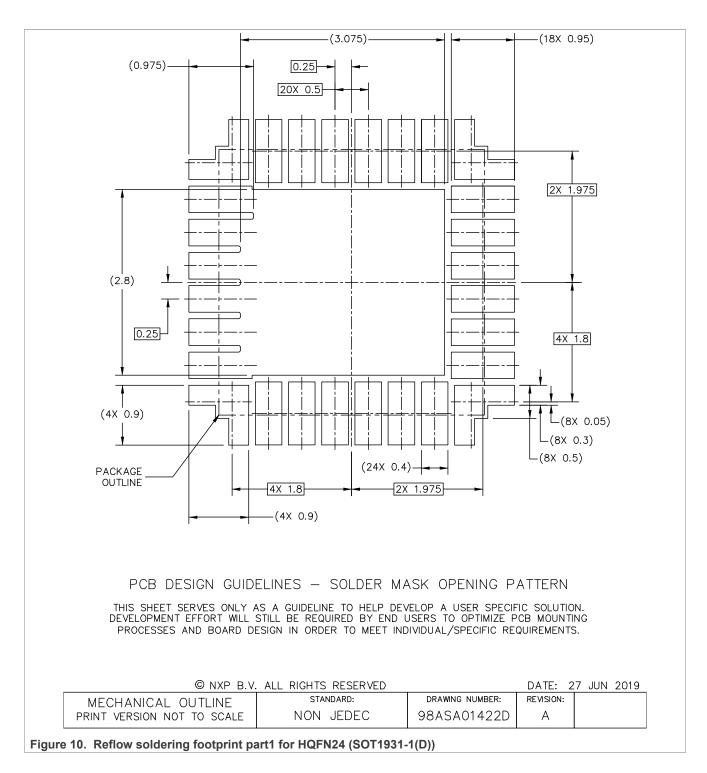
Consult the most recently issued drawing before initiating or completing a design.

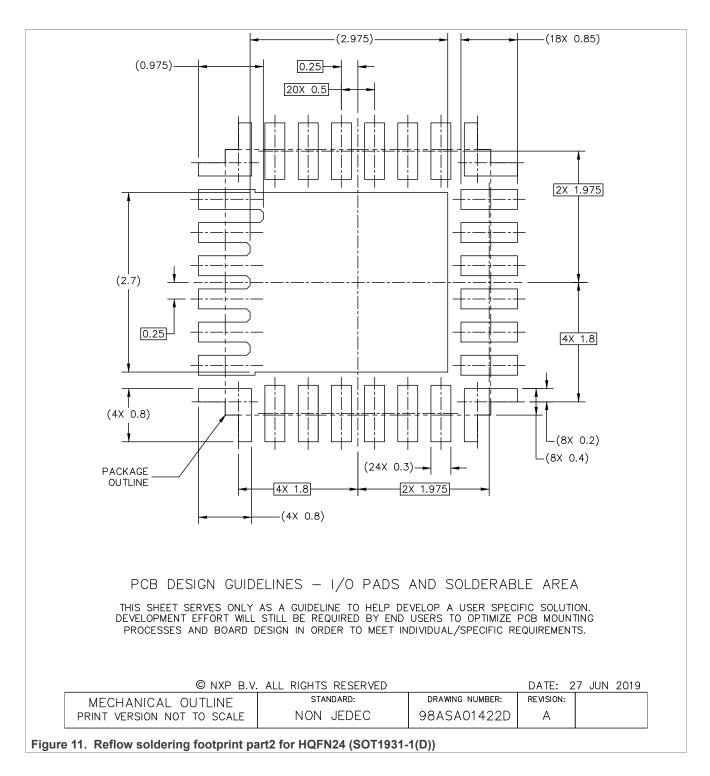
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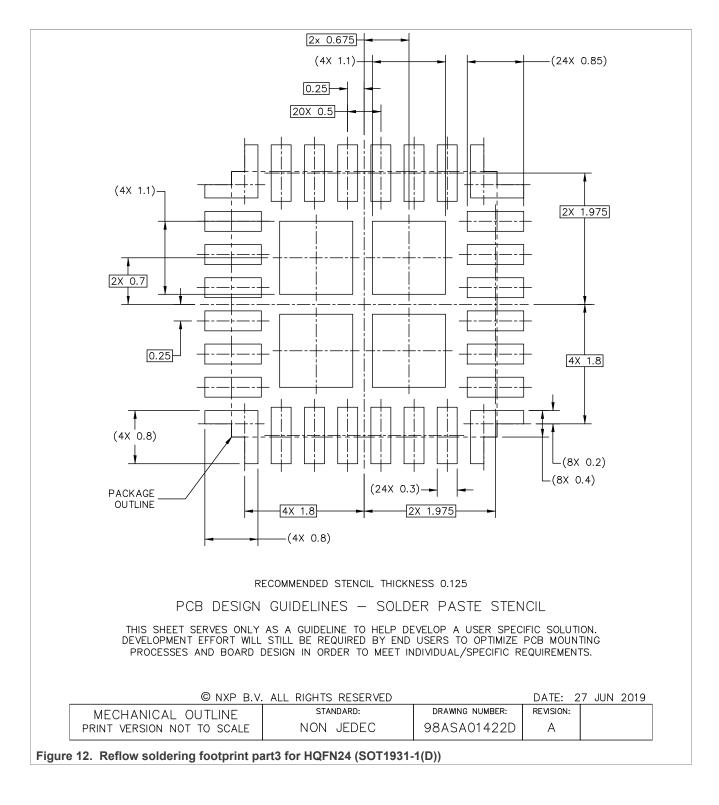
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NOTES:				
1. ALL DIMENSIONS ARE IN	MILLIMETERS.			
2. DIMENSIONING AND TOLEF	ANCING PER ASME Y14.5M-	1994.		
3 PIN 1 FEATURE SHAPE, S	SIZE AND LOCATION MAY VAF	۲Y.		
4. COPLANARITY APPLIES TO	D LEADS, DIE ATTACH FLAG	AND CORNER NON-FU		PADS.
5. ANCHORING PADS.				
6. STEP-CUT IS APPLIED FO	OR BURR REMOVAL ONLY.			
© NXP B.V.	ALL RIGHTS RESERVED		DATE: 2	7 JUN 2019
MECHANICAL OUTLINE	STANDARD:	DRAWNG NUMBER:	REVISION:	
PRINT VERSION NOT TO SCALE	NON JEDEC	98ASA01422D	А	

Figure 13. Package outline notes HQFN24 (SOT1931-1(D))

## **10 References**

#### **NXP** reference documents

- UM11227, NTM88 family of tire pressure monitor sensors [1]
- NXP Specification NXPOMS-1719007347-17056, Media Stress Methodologies for Sensors, Contact your NXP sales [2] representative for more information
- AN1902, Assembly guidelines for QFN (quad flat no-lead) and SON (small outline no-lead) packages [3]

## 11 Revision history

Document ID	Release date	Description
	15 November 2024	<ul> <li>NTM88Kxx5S v.3.0 supersedes NTM88Kxx5S v.2.0.</li> <li>NTM88Kxx5S v.2.0 is a product data sheet. Revised the status from "Preliminary" to "Product".</li> <li>Section 1, removed "single- or " from the the first paragraph.</li> <li>Section 3, Table 2, revised as follows: <ul> <li>NTM88K135ST1: removed footnote 2 that read "Product under development consult your NXP sales representatives for samples."</li> <li>NTM88K145ST1: inserted new row.</li> <li>NTM88K155ST1; inserted new row.</li> <li>Section 6.8, Table 12, revised "T<sub>DRIFT</sub>" to "T<sub>STAB</sub>" and revised the parameter description from "Temperature drift" to "Temperature measurement stability range".</li> </ul> </li> <li>Section 6.9, revised as follows: <ul> <li>Table 13, revised "V<sub>DRIFT</sub>" to "V<sub>STAB</sub> and revised the parameter description from "Voltage measurement drift" to "Voltage measurement stability range".</li> </ul> </li> <li>Table 14, revised "GxDRIFT" to "GxSTAB" and revised the parameter description from "Voltage measurement drift" to "Voltage measurement stability range".</li> <li>Pressure measurement characteristic (90 kPa to 930 kPa) range, Table 1, removed the last row "P<sub>drift</sub>".</li> <li>Section 6.11.1, Table 16, revised "A<sub>DRIFT</sub>" to "A<sub>STAB</sub>" and revised the associate parameter from "Inertia drift" to "Acceleration measurement stability range".</li> </ul>
		<ul> <li><u>Section 7.1</u>, revised "1200 kPa" to "1518 kPa" in the conditions for P<sub>burst1k</sub> and AP1k.</li> <li><u>Section 9</u>, removed the sentence "The drawings are available for download at https://www.nxp.com/docs/en/package-information/SOT1931-1_D.pdf." from the first paragraph.</li> </ul>
NTM88Kxx5S v.2.0	6 June 2024	<ul> <li>NTM88Kxx5S v.2.0 supersedes NTM88Kxx5S v.1.0.</li> <li>NTM88Kxx5S v.2.0 is a preliminary data sheet.</li> <li>Section 2, revised "Six-channel, 8-, 10-, or 12-bit analog-to-digital converter (ADC10) with two external I/O inputs" to "Six-channel, 8-, 10-, or 12-bit analog-to-digital converter with two external I/O inputs".</li> <li>Section 5.2, Table 3, revised as follows: <ul> <li>RST_B: Removed "/ V<sub>PP</sub> programming voltage" from the Function and revised the first paragraph in the description.</li> <li>GND: revised the first sentence of the description.</li> <li>Section 6.10.1, Section 6.10.1, revised the table adding additional rows, revising values and updating references in the notes column.</li> </ul> </li> <li>Section 7.1, Table 20, removed the row A<sub>CROSS</sub> from the table.</li> <li>Section 7.2, revised the specification and added a note.</li> <li>Section 10, revised the NXP specification entry number and title.</li> </ul>
NTM88Kxx5S v.1.0	7 September 2022	<ul> <li>NTM88Kxx5S v.1.0 supersedes NTM88xxx5S v.1.2. This document supersedes NTM88xxx5S v.1.2 for the relevant part numbers in <u>Section 3</u>, <u>Table 2 "Ordering options"</u>.</li> <li>NTM88Kxx5S v.1.0 is an objective data sheet.</li> </ul>
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### Tire pressure monitor sensor

#### Table 21. Revision history...continued

Document ID	Release date	Description
		Initial release.

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## Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[1] Please consult the most recently issued document before initiating or completing a design.

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Product data sheet

NTM88KXX5S

Tire pressure monitor sensor

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